

COPY OF PAPERS ORIGINALLY FILED 5/17/0

2811\$

Amber.5342A

CHNOLOGY CENTER 2800

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

APPLICANT:

Eugene A. Fitzgerald

GROUP:

2811

SERIAL NO:

09/761,508

EXAMINER: Unknown

FILED:

January 16, 2001

FOR:

LOW THREADING DISLOCATION DENSITY RELAXED

MISMATCHED EPILAYERS WITHOUT HIGH TEMPERATURE

GROWTH

Box No Fee Amendment Assistant Commissioner of Patents Washington, D.C. 20231

Sir:

AMENDMENT

In response to the Office Action mailed December 6, 2001, please amend the application as follows:

IN THE CLAIMS:

17. (Amended) The structure of claim 16, wherein said substrate comprises Si and said first and second layers comprise [SiGe] $\underline{Si_{1-x}Ge_x}$.

05/01/2002 SBEBREGI 00000089 09761508

%1 FE:116

400,00 OF

REMARKS

Claim 17 is objected to for not being consistent with the specification. Accordingly, claim 17 has been amended in accordance with the request of the Examiner.

Claims 1-30 are rejected under 35 USC §103 as being unpatentable over Jewell '864 in view of Bensahel et al. '750, Brasen et al. '205 and in view of further remarks.

A